

A non-leaded semiconductor package and a method to assemble the same

The invention relates to a non-leaded semiconductor package 5 and to a method of assembling a non-leaded semiconductor package.

US 6,498,099 discloses a method to produce a leadless semiconductor package by half etching one or both sides of the lead-frame strip. After the wire bonding and molding processes, a 10 further etching process is performed to isolate and expose the contact pads.

This process comprises many processes steps and, in particular, 15 many etching steps. Etching is a slow and, therefore, expensive manufacturing process.

It is one object of the invention to provide a non-leaded semiconductor package and a simpler and more cost-effective 20 method for producing the package.

This object of the invention is solved by the subject matter of the independent claims. Further improvements arise from the subject matter of the dependent claims.

25 A non-leaded semiconductor package is assembled using a lead-frame strip assembly. A method to produce the leadframe strip assembly according to the invention comprises the following steps. Firstly, a metal foil is provided and a carrier tape attached to one surface. A plurality of leadframes is then 30 formed in the metal foil, each leadframe comprising a die pad or die attach pad laterally surrounded by a plurality of con-

tact leads. Each leadframe comprises the design of the desired semiconductor package. Preferably, the plurality of leadframes is formed by an etching process which is, more preferably, performed from one side of the metal foil. A plurality of isolated individual leadframes is formed.

By performing only one etching process the manufacturing process according to the invention is simplified. Performing the etching process from only one side of the metal foil leads to a simplification of the equipment required to form the leadframes and lower manufacturing costs.

Alternatively, a plurality of leadframes is formed in the metal strip by laser cutting or stamping or any method known in the art. In this embodiment of the invention the leadframes are attached to each other by thin metal joining strips and form a continuous leadframe strip. The leadframe strip is then attached to the adhesive coating of a carrier tape. The metal joining strips are then removed by, for example, etching or by laser cutting to form a plurality of isolated leadframes attached to the carrier tape. The etching process is performed from only one side of the leadframe strip. This method has the advantage that the laser cutting or stamping process is relatively fast so that the manufacturing time is reduced.

The leadframe strip assembly according to the invention therefore comprises a metal foil attached to a carrier tape. The metal foil includes a plurality of leadframes preferably arranged in a regular array of columns and rows in the metal foil. Each leadframe comprises a die attach pad laterally surrounded by a plurality of contact leads. The arrangement of

the contact leads and the die attach pad relates to the desired package design.

Preferably, the die pad and contact leads of each leadframe of the leadframe strip include anchorage features. Typically, the side walls of the die pad and inner side walls of the contact leads include protruding portions formed by an approximately square cut-out section at the base of the side walls. The protruding portion therefore extends approximately horizontally from the side walls of the die attach pad and inner side walls of the contact leads and typically has an approximately square cross-section. The upper surface of the protruding portion lies on approximately the same plane as the upper surface of the die attach pad and contact leads. This protruding portion is the anchorage feature which advantageously improves the reliability of the package.

Preferably, the die pad and contact leads of each leadframe of the leadframe strip assembly are spatially isolated from each other and, preferably, each leadframe of the metal foil of the leadframe strip assembly is spatially isolated from its neighbour. The die pad and contact leads of each leadframe are laterally isolated and are not attached to each other. Each leadframe is also laterally isolated and is not attached to the neighbouring leadframes. The isolated leadframes are mechanically supported by the carrier tape. This arrangement of the leadframe strip assembly according to the invention is advantageous in that the cutting and stripping processes used in conventional leadframe manufacturing processes are avoided. 30 This manufacturing line is therefore simplified.

Additionally, by isolating the contact leads, a space is created between adjoining leadframes. Therefore, during the singulation process the contact leads are not cut which is extremely advantageous.

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Preferably, the carrier tape comprises a polyimide film with a silicone adhesive coating. This carrier tape material has the advantage that it has good heat resistance and, therefore, provides good mechanical support to the leadframes through the 10 manufacturing process and, in particular, during the molding process. Also the adhesive can be cleanly removed from the bottom surface of the molded leadframe module or panel at the end of the manufacturing line just prior to the singulation of the individual semiconductor packages. This reduces the complex and costly cleaning steps.

15 Preferably, the metal foil comprises copper or aluminium or one of their alloys and more preferably comprises oxygen free high conductivity (OFHC) copper. These materials have good 20 electrical conductivity, are relatively inexpensive and can be easily processed.

The metal foil preferably comprises a thickness of approximately 1 mm to approximately 0.01 mm or more preferably approximately 0.25 mm to approximately 0.1 mm. The leadframe strip assembly according to the invention is advantageous in 25 that the thickness of the metal foil which is used to form the plurality of leadframes can be thinner than that used in conventional processes as the carrier tape provides mechanical support. Also, in the method according to the invention the 30 whole surface area of the metal strip is not thinned by an etching process to create leadframes of the desired thickness.

The materials cost and manufacturing time is, therefore, reduced.

The leadframe strip may be partly or completely covered by an
5 electro-plated coating. Different parts, such as the die attach pad, the contact leads and the contact areas of the contact leads, of a leadframe may be coated in different materials. The electro-plated coating may comprise silver, nickel/palladium/gold or nickel/nickel phosphorous.

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In the next stage of the process a semiconductor die, which includes an active surface with a plurality of die contact pads and a passive surface, is attached to each die attach pad of the leadframe strip assembly. Each die is electrically connected to the leadframe by a plurality of bond wires connecting the die contact pads and the lead contact areas of the contact leads.

The plurality of dies attached to the leadframe strip assembly, contact leads, wire bonds and upper surface of the carrier tape are then encapsulated with mold material forming a panel or molded leadframe module. The mold material is typically a polymeric-based material.

25. A method to assemble a non-leaded semiconductor package according to the invention comprises the following steps. The panel or molded leadframe module formed by the leadframe strip assembly process is provided and the carrier tape attached to the bottom surface is removed. The individual non-leaded semiconductor packages are singulated from the panel by sawing.

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The sawing process may be performed by a saw blade, water jet or laser. The leadframe strip assembly according to the invention provides a panel in which the packages are singulated by cutting through only the mold material as the leadframe strip assembly includes isolated leadframes, die attach pads and contact leads. This greatly simplifies the sawing process.

If a saw blade is used to cut through two different materials, cracks can form between the two materials, burr formation is a problem and the wear rate of the saw blade is increased. Water jet technology is extremely slow and, therefore, may be impractical for high volume production as it is too costly. If a laser beam is used to cut through two types of material then the intensity must be adjusted which leads to a complicated process. These problems are avoided by the leadframe strip assembly according to the invention.

The leadframe strip assembly and the method of the invention is advantageously used to produce very thin quad flat non-leaded (VQFN) packages and particularly for packages of the pancake design leadframe which include a plurality of adjoining leadframes.

An embodiment of the invention will now be described by way of example with reference to the drawings.

Figure 1 shows a non-leaded semiconductor package according to the invention,

Figure 2 shows a cross-sectional view of a section of a copper foil with a carrier tape according to the invention,

Figure 3 shows a cross-sectional view of a section of the copper strip of Figure 2 after an etching process to form a plurality of isolated leadframes, each having isolated contact leads,

5 Figure 4 shows a cross-sectional view of a section of the leadframe strip assembly of Figure 3 after a die attach and a wire-bonding process,

Figure 5 shows a cross-sectional view of a section of the leadframe strip assembly of Figure 4 after a molding process, and

10 Figure 6 shows a cross-sectional view of a section of the leadframe strip assembly of Figure 5 during a singulation process.

15 Figure 1 shows a non-leaded semiconductor package 1 according to the invention. The package 1 comprises a semiconductor die 2 and a leadframe 3. The leadframe 3 comprises a die attach pad 4 in approximately its lateral centre which is laterally surrounded by a plurality of contact leads 5. The die attach pad 4 and contact leads 5 have essentially the same thickness and lie on essentially the same lateral plane. The inner ends of the contact leads 5 include lead contact areas 6. The side walls of the die attach pad 4 and the inner side wall of the contact leads 5 include a protruding portion 19 whose upper surface lies on approximately the same plane as that of the upper surface of the die attach pad or contact lead. The protruding portions 19 have an approximately square cross-section. The leadframe 3 comprises oxygen-free high conductivity copper.

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30 The semiconductor die 2 includes an active surface with a plurality of die contact pads 7 and a passive surface. The pas-

sive surface of the die 2 is attached approximately in the lateral centre of the die attach pad 4 by die attach material 8. The die 2 is electrically connected to the leadframe 3 by a plurality of bond wires 9 which connect the die contact pads 7 5 and the lead contact areas 6.

The upper surface of the die 2, contact leads 5, bond wires 9 and space between the die pad 4 and contact leads 5 is encapsulated with mold material 10. The bottom surface 11 of the 10 non-leaded package 1 comprises mold material 10 and the bottom surfaces of the die attach pad 4 and contact leads 5 on an essentially common plane. The outer side surfaces of the contact leads 5 are covered by a thin coating of the mold material 10. The outer sides of the semiconductor package 1 are essentially 15 vertical. The bottom surfaces of the contact leads 5 provide the external contact areas of the package 1.

Figure 2 shows a copper foil 12 attached to a carrier tape 13 in the first step of the method according to the invention to 20 manufacture very thin quad flat non-leaded (VQFN) packages. The copper foil comprises oxygen-free high conductivity copper and comprises a thickness of between approximately 0.25mm and approximately 0.1mm. The copper strip 12 is attached to the adhesive coating 17 on the upper surface of a carrier tape 13 25 which comprises a polyimide film substrate with a layer of silicone adhesive 17 on its upper surface.

Figure 3 shows the next stage of the method according to the invention in which a plurality of leadframes 3 are formed in 30 the copper foil 1. The leadframes 3 formed by a selective etching process which takes place on one side, from the top as

shown in Figure 2, of the copper strip 12. The upper surface of the carrier tape 13 acts as an etch stop.

The leadframes 3 are laterally arranged in a regular array of 5 rows and columns in the copper foil 12. Each leadframe 3 includes a die attach pad 4 in the centre which is laterally surrounded by a plurality of contact leads 5. The lateral arrangement of the plurality of leadframes and the lateral arrangement of each individual leadframe cannot be seen in the 10 cross-sectional views of the figures.

The contact leads 5 are separate from the die attach pad 4 and are not connected to each other. Each leadframe 3 is laterally isolated from the neighbouring leadframes in the copper foil 15 12 and the bottom surface of each leadframe is attached to the adhesive coating 17 of the carrier tape 13. The carrier tape 13 provides the mechanical support to the isolated leadframes 3, each including an isolated die attach pad 4 and a plurality of isolated contact leads 5 during the next stages of the 20 manufacturing process up to just prior to the singulation process.

In the next step in the process, shown in Figure 4, a semiconductor die 2 is attached using die attach material 8 to the 25 die pad 4 of each leadframe 3 in the copper foil 12. The semiconductor die 2 includes an active upper surface including a plurality of die contact pads 7. The inner portion of each contact lead 5 of the leadframe 3 also includes a contact area 6. The electrical connection between the contact pads 7 of the 30 semiconductor die 2 and the contact areas 6 of the contact leads 5 of the leadframe 3 is formed by wire bonds 9.

Figure 5 shows the molding process of the method according to the invention. The plurality of leadframes 3 is encapsulated by mold material 10 to form a molded leadframe module or panel 14. The die 2, die attach pad 4, contact leads 5, wire bonds 9 and areas between the contact leads 5, die attach pads 4 and the upper surface of the carrier tape 13 of each of a plurality of leadframes 3 are encapsulated by a single mass of mold material 10. The upper surface of the carrier tape 13 acts as the bottom surface of the mold. The mold material is then given an appropriate curing treatment.

Figure 6 shows the final step of the process in which the carrier tape 13 is removed from the molded leadframe module 14. The bottom surface 16 of the molded leadframe module 14 comprises mold material 10 and isolated areas comprising the bottom metal surfaces of the die attach pads 4 and isolated contact leads 5 on an essentially common surface. The individual non-leaded packages 1 are singulated from the molded leadframe module 14 by sawing through the mold material 10 between the individual leadframes 3 as indicated by the dotted lines 15 and saw blade 18.

Contacting means, such as solder balls, are then attached to the bottom surface of the contact leads 5 and provide the external contacts from the non-leaded package 1 to, for example, a printed circuit board. Alternatively, the solder balls may be attached to the contact leads 5 while the package forms part of the molded leadframe module. The packages 1 are then tested, packages and then mounted on, for example, a printed circuit board.

Reference Numbers

- 1 non-leaded semiconductor package
- 2 semiconductor die
- 5 3 leadframe
- 4 die attach pad
- 5 contact lead
- 6 contact lead contact area
- 7 die contact pad
- 10 8 die attach material
- 9 wire bond
- 10 mold material
- 11 bottom surface of package
- 12 non-leaded package
- 15 13 carrier tape
- 14 molded leadframe module
- 15 singulation lines
- 16 bottom surface of leadframe module
- 17 adhesive coating
- 20 18 saw blade
- 19 protruding portion